

GP2M009A090FG

GP2M009A090FG Information

www.helsenezcom	GP2M009A090FG Global Power Technologies Group Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 900V 9A TO220F TO-220-3 Full Pack For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



GP2M009A090FG Specifications

Manufacturer Part Number	GP2M009A090FG
Manufacturer	Global Power Technologies Group
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3 Full Pack
Series	
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	900V
Current - Continuous Drain (Id) @ 25°C	9A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	72nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2740pF @ 25V
Vgs (Max)	$\pm 30 V$
FET Feature	-
Power Dissipation (Max)	89W (Tc)
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 4.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220F
Package / Case	TO-220-3 Full Pack
	Report errors?

GP2M009A090FG Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

GP2M009A090FG Payment Methods





If you have any question about GP2M009A090FG, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com